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## P25 - Proton Beam Writing combined with controlled subsequent electrochemical etching for the three-dimensional microstructuring of p-GaAs and p-InP for MEMS applications

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Nowadays, an increasing demand on microelectromechanical systems can be found in the field of capacitive accelerometers, pressure sensors or energy harvesters [1,2].

Three-dimensional microstructures needed for those applications have already been fabricated with the lithographic technique Proton Beam Writing [3].

In particular, just by variation of the irradiation fluence, Proton Beam Writing in combination with fluence depending electrochemical etching proved to be promising for three-dimensional semiconductor microstructuring [4].

Recently, a controlled fabrication of free-standing or undercut structures was possible due to finite element simulations of the electrochemical etching rates [5].

We are going to present our latest results regarding the microstructuring of p-GaAs and p-InP.

[1] V. Cimalla, J. Pezoldt, and O. Ambacher, *J. Phys. D: Appl. Phys.*, 40(20), 6386, 2007

[2] J. A. Paradiso and T. Starner, *IEEE Pervasive Comput.*, 4(1), 18-27, 2005

[3] J.A. van Kan et al., *Appl. Phys. Lett.*, 83(8), 1629, 2003

[4] M. Schulte-Borchers, U. Vetter, T. Koppe, H. Hofsäss, *J. Micromech. Microeng.*, 22, 025011, 2012.

[5] T. Koppe, C. Rothfuchs, M. Schulte-Borchers, H. Hofsäss, H. Boudinov, U. Vetter, *IEEE J. Microelectromech. Syst.*, In Press, Accepted Manuscript, 2014

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**Session Classification:** Poster Session with Cheese and Wine